

# **isc Silicon NPN Power Transistor**

**BD609** 

### **DESCRIPTION**

- · Collector-Emitter Breakdown Voltage-
  - : V<sub>(BR)CEO</sub>= 80V(Min)
- Complement to Type BD610
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### **APPLICATIONS**

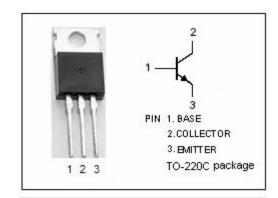
 Designed for use in high power audio amplifiers utilizing complementary or quasi complementary circuits.

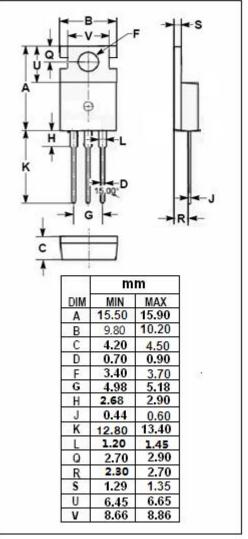
## ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

| SYMBOL           | PARAMETER                                | VALUE   | UNIT         |
|------------------|--|---------|--------------|
| V <sub>CBO</sub> | Collector-Base Voltage                   | 80      | V            |
| Vceo             | Collector-Emitter Voltage                | 80      | V            |
| $V_{EBO}$        | Emitter-Base Voltage                     | 5       | V            |
| Ic               | Collector Current-Continuous             | 10      | Α            |
| I <sub>B</sub>   | Base Current                             | 6       | Α            |
| Pc               | Collector Power Dissipation<br>@ Tc=25°C | 90      | W            |
| TJ               | Junction Temperature                     | 150     | $^{\circ}$ C |
| T <sub>stg</sub> | Storage Temperature Range                | -55~150 | $^{\circ}$   |

#### THERMAL CHARACTERISTICS

| SYMBOL              | PARAMETER                            | MAX  | UNIT |
|---------------------|--------------------------------------|------|------|
| R <sub>th j-c</sub> | Thermal Resistance, Junction to Case | 1.39 | °C/W |







## **ISC Silicon NPN Power Transistor**

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#### **ELECTRICAL CHARACTERISTICS**

T<sub>c</sub>=25℃ unless otherwise specified

| SYMBOL                | PARAMETER                            | CONDITIONS   | MIN | MAX | UNIT |
|-----------------------|--------------------------------------|--|-----|-----|------|
| V <sub>CEO(SUS)</sub> | Collector-Emitter Sustaining Voltage | I <sub>C</sub> = 30mA ;I <sub>B</sub> = 0                                | 80  |     | V    |
| V <sub>CE(sat)</sub>  | Collector-Emitter Saturation Voltage | I <sub>C</sub> = 3A; I <sub>B</sub> = 0.3A                               |     | 1.1 | V    |
| V <sub>BE(on)</sub>   | Base-Emitter On Voltage              | I <sub>C</sub> = 4A ; V <sub>CE</sub> = 2V                               |     | 1.6 | V    |
| I <sub>CBO</sub>      | Collector Cutoff Current             | V <sub>CB</sub> = 80V;I <sub>E</sub> = 0                                 |     | 1.0 | mA   |
| I <sub>EBO</sub>      | Emitter Cutoff Current               | V <sub>EB</sub> = 5V; I <sub>C</sub> = 0                                 |     | 2.0 | mA   |
| h <sub>FE-1</sub>     | DC Current Gain                      | I <sub>C</sub> = 2A ; V <sub>CE</sub> = 2V                               | 30  |     |      |
| h <sub>FE-2</sub>     | DC Current Gain                      | I <sub>C</sub> = 4A ; V <sub>CE</sub> = 2V                               | 15  |     |      |
| f <sub>T</sub>        | Current-Gain—Bandwidth Product       | I <sub>C</sub> = 1.0A; V <sub>CE</sub> = 10V; f <sub>test</sub> = 1.0MHz | 1.5 |     | MHz  |

## **NOTICE:**

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